

## IGBT MODULE ( P-Series )

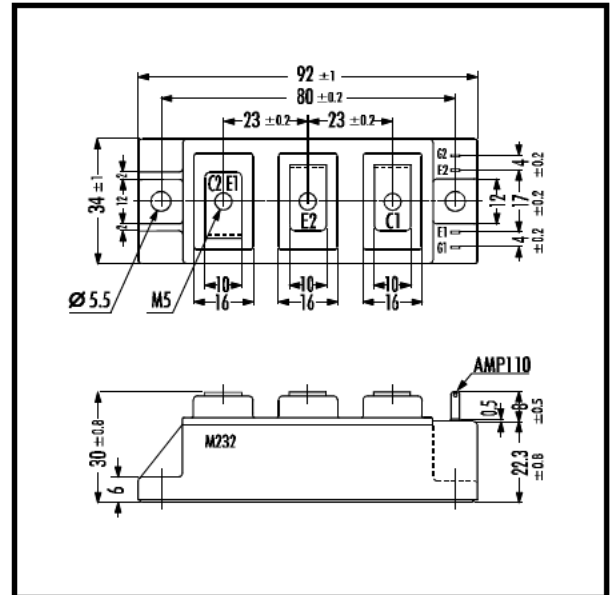
### Features

- Square SC SOA at  $10 \times I_C$
- Simplified Parallel Connection
- Narrow Distribution of Characteristics
- High Short Circuit Withstand-Capability

### Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

### Outline Drawing



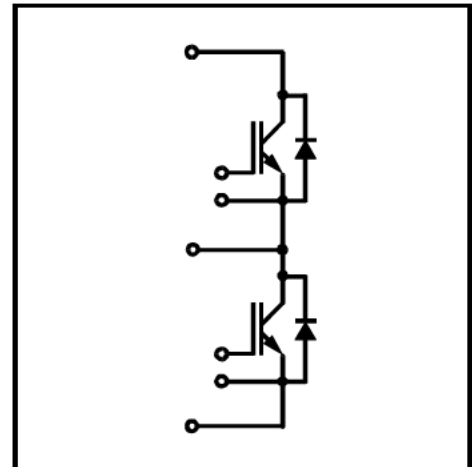
### Maximum Ratings and Characteristics

#### Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

| Items                     | Symbols                           | Rated Values               | Units            |
|---------------------------|-----------------------------------|----------------------------|------------------|
| Collector-Emitter Voltage | $V_{CES}$                         | 1400                       | V                |
| Gate -Emitter Voltage     | $V_{GES}$                         | $\pm 20$                   | V                |
| Collector Current         | Continuous $T_c=25^\circ\text{C}$ | 75                         | A                |
|                           |                                   | 50                         |                  |
|                           | 1ms $T_c=25^\circ\text{C}$        | 150                        |                  |
|                           |                                   | 1ms $T_c=80^\circ\text{C}$ |                  |
|                           |                                   | $-I_C$                     |                  |
|                           | $-I_C$ PULSE                      | 100                        |                  |
| Max. Power Dissipation    | $P_C$                             | 400                        | W                |
| Operating Temperature     | $T_j$                             | +150                       | $^\circ\text{C}$ |
| Storage Temperature       | $T_{stg}$                         | -40 ~ +125                 | $^\circ\text{C}$ |
| Isolation Voltage         | A.C. 1min. $V_{is}$               | 2500                       | V                |
| Screw Torque              | Mounting *1                       | 3.5                        | Nm               |
|                           | Terminals *2                      | 3.5                        |                  |

Note: \*1:Recommendable Value; 2.5 ~ 3.5 Nm (M5)

### Equivalent Circuit

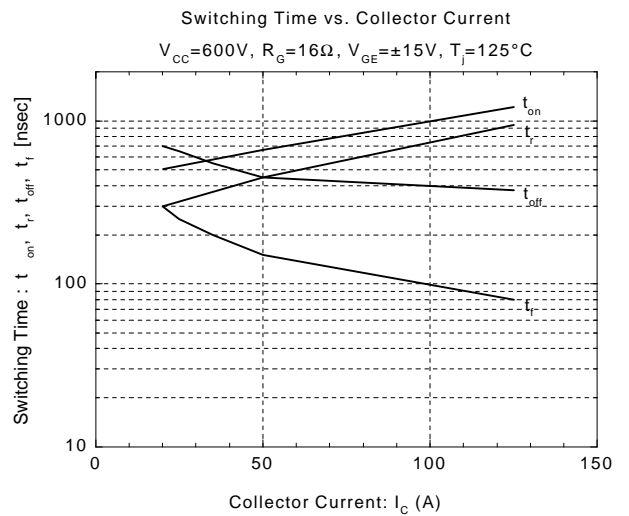
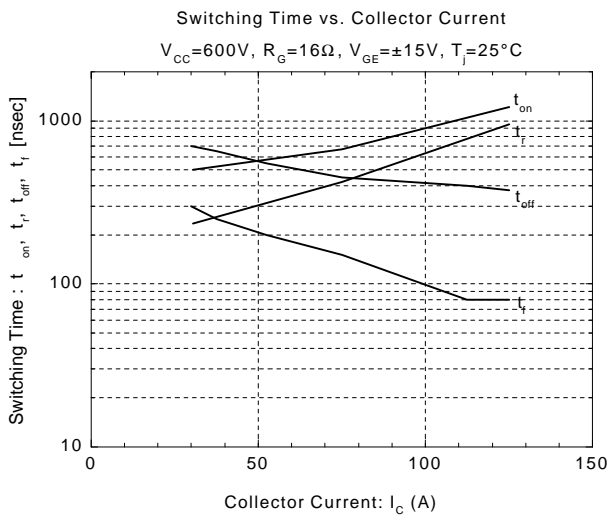
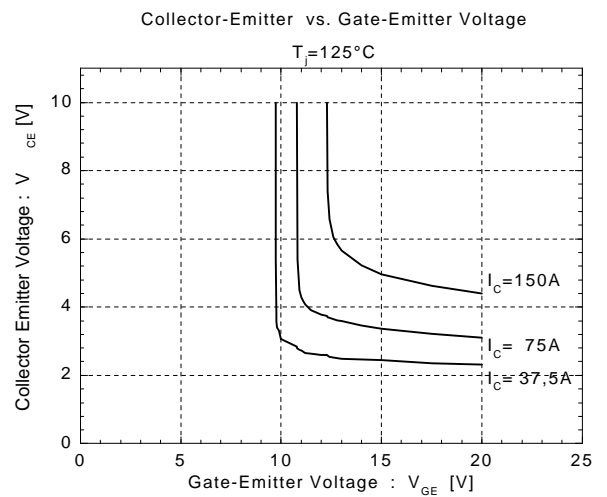
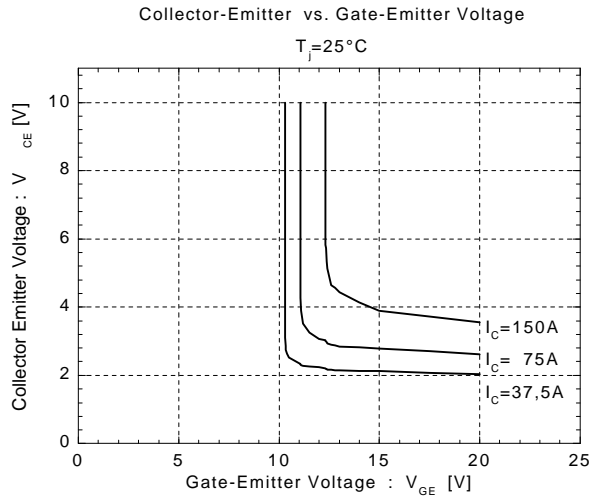
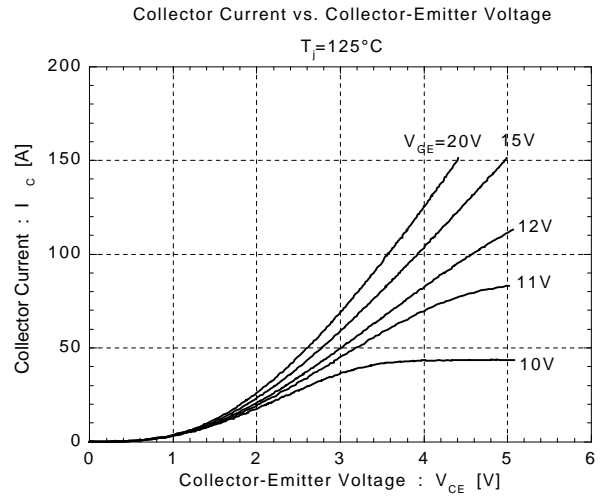
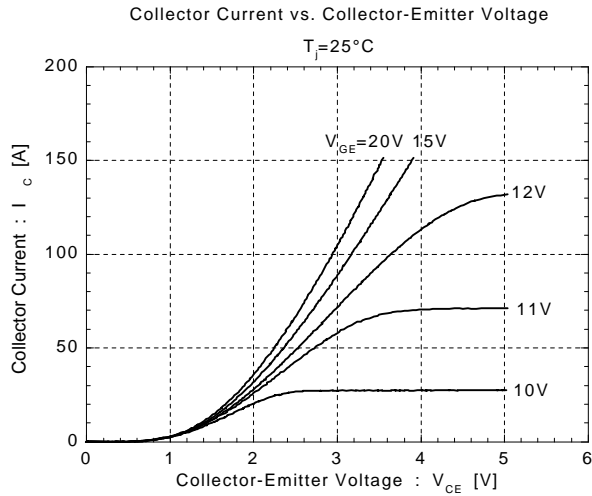


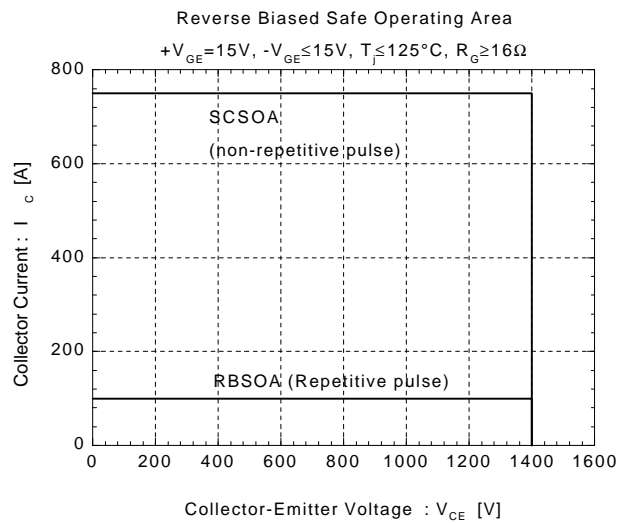
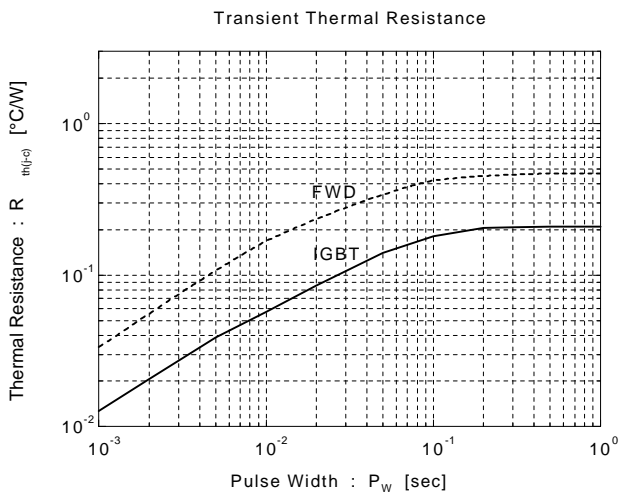
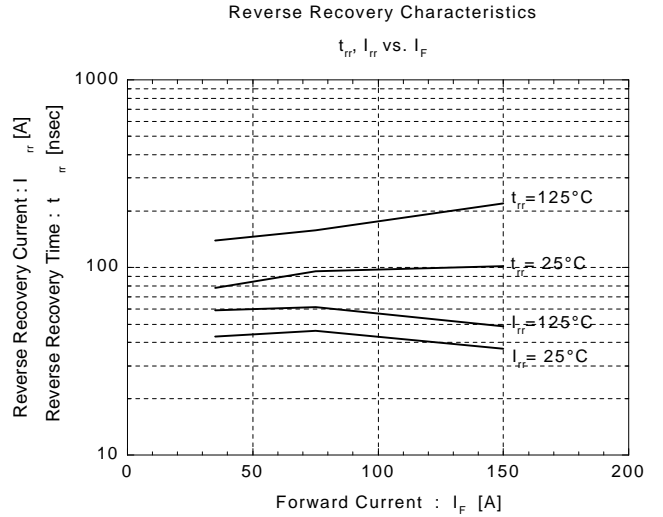
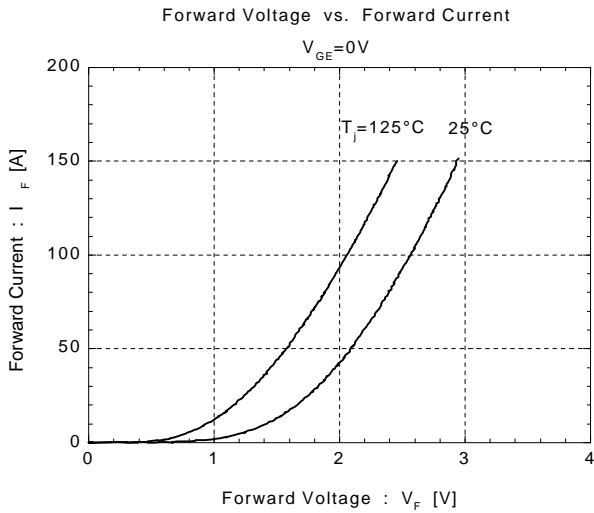
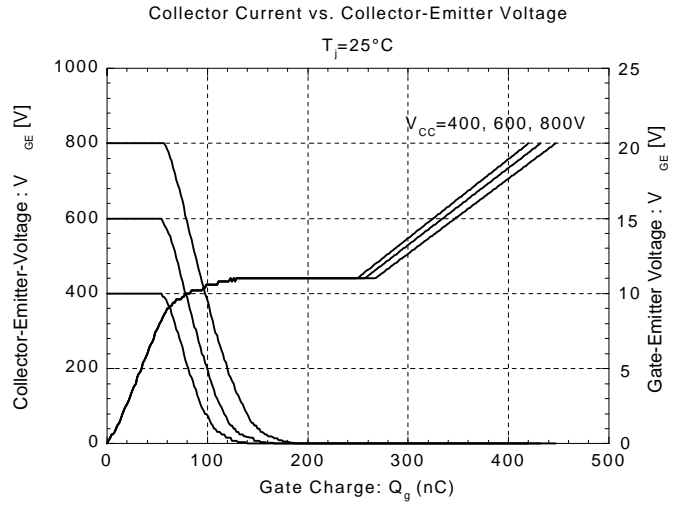
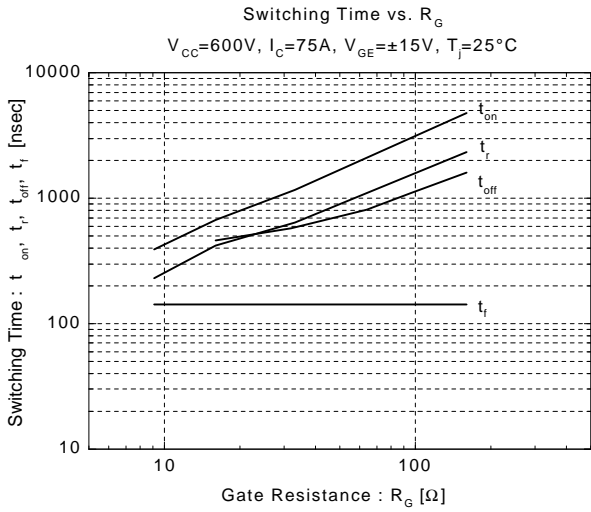
#### Electrical Characteristics ( at $T_j=25^\circ\text{C}$ )

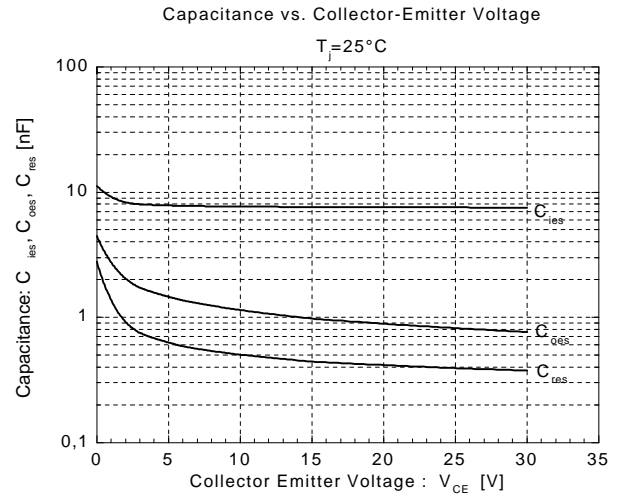
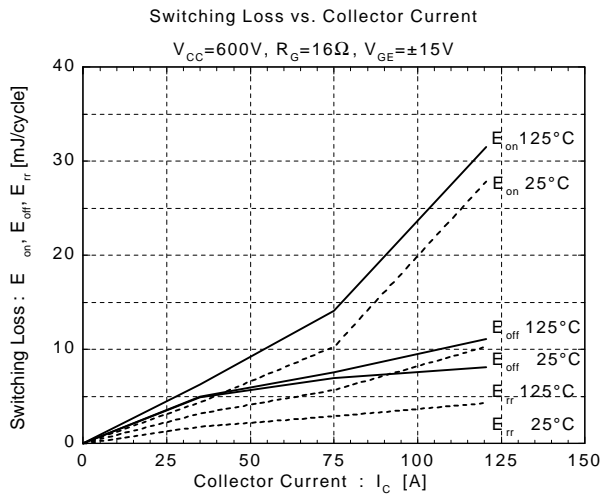
| Items                                | Symbols       | Test Conditions                                       | Min. | Typ. | Max. | Units         |
|--------------------------------------|---------------|---|------|------|------|---------------|
| Zero Gate Voltage Collector Current  | $I_{CES}$     | $V_{GE}=0V$ $V_{CE}=1400V$                            |      |      | 1.0  | mA            |
| Gate-Emitter Leakage Current         | $I_{GES}$     | $V_{CE}=0V$ $V_{GE}=\pm 20V$                          |      |      | 200  | $\mu\text{A}$ |
| Gate-Emitter Threshold Voltage       | $V_{GE(th)}$  | $V_{GE}=20V$ $I_C=50\text{mA}$                        | 6.0  | 8.0  | 9.0  | V             |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $T_j=25^\circ\text{C}$ $V_{GE}=15V$ $I_C=50\text{A}$  |      | 2.7  | 3.0  | V             |
|                                      |               | $T_j=125^\circ\text{C}$ $V_{GE}=15V$ $I_C=50\text{A}$ |      | 3.3  |      |               |
| Input capacitance                    | $C_{ies}$     | $V_{GE}=0V$   |      | 5000 |      | pF            |
| Output capacitance                   | $C_{oes}$     | $V_{CE}=10V$  |      | 750  |      |               |
| Reverse Transfer capacitance         | $C_{res}$     | $f=1\text{MHz}$                                       |      | 330  |      |               |
| Turn-on Time                         | $t_{ON}$      | $V_{CC}=600V$<br>$I_C=50\text{A}$                     |      |      | 1.2  | $\mu\text{s}$ |
|                                      | $t_r$         |   |      |      | 0.6  |               |
| Turn-off Time                        | $t_{OFF}$     | $V_{GE}=\pm 15V$<br>$R_G=2.4\Omega$                   |      |      | 1.0  | $\mu\text{s}$ |
|                                      | $t_f$         |   |      |      | 0.3  |               |
| Diode Forward On-Voltage             | $V_F$         | $I_F=50\text{A}$ $V_{GE}=0V$                          |      | 2.4  | 3.3  | V             |
| Reverse Recovery Time                | $t_{rr}$      | $I_F=50\text{A}$                                      |      |      | 350  | ns            |

### Thermal Characteristics

| Items              | Symbols       | Test Conditions       | Min. | Typ. | Max. | Units              |
|--------------------|---------------|-----------------------|------|------|------|--------------------|
| Thermal Resistance | $R_{th(j-c)}$ | IGBT                  |      |      | 0.31 | $^\circ\text{C/W}$ |
|                    | $R_{th(j-e)}$ | Diode                 |      |      | 0.66 |                    |
|                    | $R_{th(c-f)}$ | With Thermal Compound |      | 0.05 |      |                    |







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